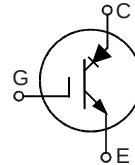


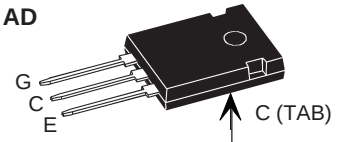
IGBT with Reverse Blocking capability

IXRH 50N120
IXRH 50N100

$V_{CES} = 1000 / 1200 \text{ V}$
 $I_{C25} = 60 \text{ A}$
 $V_{CE(sat)} = 2.5 \text{ V}$
 $t_f = 75 \text{ ns}$



TO-247 AD



G = Gate,
E = Emitter,

C = Collector,
TAB = Collector

IGBT

Symbol	Conditions	Maximum Ratings		
V_{CES}	$T_{VJ} = 25^{\circ}\text{C}$ to 150°C	IXRH 50N120 IXRH 50N100	± 1200 ± 1000	V V
V_{GES}			± 20	V
I_{C25}	$T_C = 25^{\circ}\text{C}$		60	A
I_{C90}	$T_C = 90^{\circ}\text{C}$		40	A
I_{CM}	$V_{GE} = 0/15 \text{ V}$; $R_G = 22 \Omega$; $T_{VJ} = 125^{\circ}\text{C}$		80	A
V_{CEK}	RBSOA, Clamped inductive load; $L = 100 \mu\text{H}$		500	V
P_{tot}	$T_C = 25^{\circ}\text{C}$		300	W

Symbol	Conditions	Characteristic Values ($T_{VJ} = 25^{\circ}\text{C}$, unless otherwise specified)		
		min.	typ.	max.
$V_{CE(sat)}$	$I_C = 40 \text{ A}$; $V_{GE} = 15 \text{ V}$; $T_{VJ} = 25^{\circ}\text{C}$ $T_{VJ} = 125^{\circ}\text{C}$		2.5 3.0	3.1 V
$V_{GE(th)}$	$I_C = 2 \text{ mA}$; $V_{GE} = V_{CE}$	4		8 V
I_{CES}	$V_{CE} = 0.8 V_{CES}$; $V_{GE} = 0 \text{ V}$; $T_{VJ} = 25^{\circ}\text{C}$ $T_{VJ} = 125^{\circ}\text{C}$		3.0	0.4 mA mA
I_{GES}	$V_{CE} = 0 \text{ V}$; $V_{GE} = \pm 20 \text{ V}$			500 nA
$t_{d(on)}$ t_r $t_{d(off)}$ t_f E_{on} E_{off}	Inductive load, $T_{VJ} = 125^{\circ}\text{C}$ $V_{CE} = 500 \text{ V}$; $I_C = 40 \text{ A}$ $V_{GE} = 0/15 \text{ V}$; $R_G = 22 \Omega$		80 100 380 75 3.6 2.1	ns ns ns ns mJ mJ
C_{ies}			4	nF
Q_{Gon}			150	nC
I_{RM} t_{rr}			58 840	A ns
R_{thJC}				0.42 K/W

Features

- IGBT with NPT (non punch through) structure
- reverse blocking capability independent from gate voltage
 - function of series diode monolithically integrated
 - no external series diode required
 - soft reverse recovery
- positive temperature coefficient of saturation voltage
 - optimum current distribution when paralleled
- Epoxy of TO 247 package meets UL 94V-0

Applications

converters requiring reverse blocking capability:

- current source inverters
- matrix converters
- bi-directional switches
- resonant converters
- induction heating
- auxiliary switches for soft switching in the main current path

IXYS reserves the right to change limits, test conditions and dimensions.

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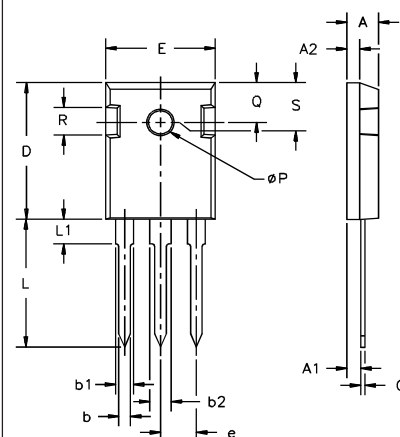
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Component

Symbol	Conditions	Maximum Ratings	
T_{VJ}		-55...+150	°C
T_{stg}		-55...+125	°C
M_d	mounting torque	0.8 - 1.2	Nm
F_c	mounting force with clip	20...120	N

Symbol	Conditions	Characteristic Values		
		min.	typ.	max.
R_{thCH}	with heatsink compound		0.25	K/W
Weight			6	g

TO-247 AD Outline


Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.7	5.3	.185	.209
A ₁	2.2	2.54	.087	.102
A ₂	2.2	2.6	.059	.098
b	1.0	1.4	.040	.055
b ₁	1.65	2.13	.065	.084
b ₂	2.87	3.12	.113	.123
C	.4	.8	.016	.031
D	20.80	21.46	.819	.845
E	15.75	16.26	.610	.640
e	5.20	5.72	0.205	0.225
L	19.81	20.32	.780	.800
L1		4.50		.177
ØP	3.55	3.65	.140	.144
Q	5.89	6.40	0.232	0.252
R	4.32	5.49	.170	.216
S	6.15	BSC	.242	BSC